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Energetic Bilan of a Mems Conform to Emmy Noether Theorem for Extraction of Vacuum Energy

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Abstract

This theoretical work corresponds to the hope of extracting an energy present throughout the universe: that of the quantum vacuum. This article demonstrates that using quantum vacuum energy, it is theoretically possible to maintain continuous periodic vibration of a piezoelectric bridge and extract usable electrical power from it, without contradicting Emmy Noether's theorem. These vibrations of the sensor part of the proposed MEMS have nothing in common with an impossible macroscopic "perpetual motion" because the energy of the quantum vacuum permanently powers the system. They are obtained by automatically controlling the deformation of a piezoelectric bridge. This cyclic deformation is created thanks to the Casimir force F_{CA}, omnipresent, permanent and attractive, between two electrodes. This F_{CA} force is controlled by an automatic Coulomb repulsive force F_{co} which is applied, thanks to the closure of a switch n°1 on a third electrode called Coulomb. F_{co} Coulomb's force derives from the electric charges generated by the deformation of the piezoelectric bridge. The F_{co} force is in the opposite direction and with a greater intensity than the F_{co}. The F_{co} force appears and disappears at predetermined positions z1 and z2, thanks to the very close activation of two switches which automatically switch by the action of the electric charges appearing on the deformed piezoelectric bridge. The resultant of the applied forces, F_{co} - F_{ca} , then straightens the bridge and gives it kinetic energy, giving it inertia which will be dissipated by the F_{CA} force. The deformation of the piezoelectric bridge being reduced according to its electric charges, the switch n°1 opens again, immediately after its closure. Very quickly thereafter, the Coulomb electrode is then brought to ground, thanks to the switching - via an R.L.C circuit - of the switch n°2. The F_{co} force therefore disappears very quickly after its appearance. The kinetic energy acquired by the structure gives it inertia which allows it to find or slightly exceed the initial position. The Casimir force, still present, then deforms the structure again. The system starts to vibrate.

Each time switch n°2 close to ground, a current and voltage peak is generated. These periodic power peaks supply an autonomous electronic circuit (without any power supply) which transforms these signals into a usable DC voltage. In this article we will exclusively present the energy balance of the structure, and we will show that this balance is consistent with Miss Emmy Noether's fundamental theorem. For following parts:

- Putting into equations the dynamic behavior of the structure
- Creation of autonomous electronics for signal shaping
- Manufacturing microtechnology [1-3].

See the articles published on Academia at the addresses:

https://www.academia.edu/127669193/DEVICE_ELECTRONIC_TECHNOLOGY_FOR_A_M_E_M_S_WHICH_ALLOW_THE_EXTRACTION_OF_ELECTRICAL_POWER_FROM_VACUUM_ENERGY_CONFORM_TO_EMMY_NOETHER_THEOREM

Keywords: Casimir, Coulomb, Vacuum Quantum Energy Extraction, Piezoelectric, MEMS

Description of the System Introduction

We know that the quantum vacuum, the energy vacuum, the absolutely nothing, does not exist.

This statement has been proven multiple times and noted by:

Lamb's shift (1947) of atomic emission frequencies:

https://quantummechanics.ucsd.edu/ph130a/130_notes/node476.html)

• By the force of Van der Waals which plays a very important physicochemical role and had an interpretation quantum 1930 [London] when two atoms are coupled to the same fluctuations in vacuum:

https://culturesciences.chimie.ens.fr/thematiques/chimie-du-vivant/les-forces-de-van-der-waals-et-le-gecko

• By Hawking's radiation theory, predicted in 1974 and observed on September 7, 2016. Article Observation of quantum Hawking radiation and its entanglement in an analogue black hole:

https://www.nature.com/articles/nphys3863

• By the experimental verification (1958) of the existence of a force equated by Casimir in 1948. This so-called Casimir force was measured for the first time in 1997: <u>https://arxiv.org/abs/quant-ph/9907076</u> <u>https://en.wikipedia.org/wiki/</u> Casimir_effect

The undisputed interpretation of the above effects involves an energy source coming from some kind of "nothing" or more precisely from the quantum vacuum. So, it is certain that this source of energy causing unmistakable physical manifestations exists. We will therefore choose, for the remainder of this article, a reference frame consisting of the 4-dimensional "Space-time" continuum augmented by those, still unknown, in the "quantum vacuum". In this reference frame we will try to show that the mathematical theorem of the mathematician Emmy Noether is not transgressed. This important mathematical theorem involves in other things the conservation of energy:

<u>https://fr.wikiversity.org/wiki/Outils_math%C3%A9matiques_pour_la_physique_(PCSI)/</u> <u>Th%C3%A9or%C3%A8me_d%27Emmy_N%C5%93ther#</u>

In this paper we will focus essentially on presenting the detailed energy balance of a MEMS apparently capable of permanently extracting a small amount of energy from the quantum vacuum that can be used in our world. We will try to show that using a piezoelectric bridge deformed by a isotropic , atemporal , attractive, force of Casimir FCA , and straightened by a very ephemeral , repulsive , but more intense force of Coulomb FCO induced by this deformation , an apparent "perpetual movement" of the MEMS device is possible .The schematic of this M.E.M.S. is in figure 4 and 5.

In fact, the problem is less to extract energy from the vacuum than to extract it without spending more energy that we cannot hope to recover. The attractive Casimir force is $F_{CA} = S_S \frac{\pi^2 c h}{240 z_c^4}$ (Eq.1), ref [4-6]. With SS the surface

of Casimir's electrodes , $h = h/2\pi$ the reduce Planck constant, and c the speed of light, z_s the interface of Casimir's electrodes . This variation in $1/z_s^4$ of FCA , would imply that a larger opposing force is provided to return to the initial position when the interface z_s is smaller.

Coulomb's force can play this role with an energy balance satisfying Emmy Noether's theorem, because -as we shall see- this force will be in $1/z_s^{10}$: In fact, we know that the fixed charges Q_F induced by a Casimir force F_{CA} - in the case of a deformation perpendicular to the polarization of a piezoelectric film- are proportional to the Casimir force F_{CA} and are therefore in $1/z_s^4$. We have, with z_0 the initial position without any deformation of the piezoelectric film: $Q_F = \frac{d_{31} l_p}{a_p} F_{CA} \Rightarrow Q_F = \frac{d_{31} l_p}{a_p} S \frac{\pi^2 c h}{240} \left(\frac{1}{z_s^4} - \frac{1}{z_0^4} \right)$ (Eq. (2)),ref [7-9]. In this expression when $z_s = z_0$ the electric charge is null. The piezoelectric coefficient is d_{31} (CN⁻¹), l_p , a_p , are respectively length and thickness (m) of the piezoelectric bridge. Q_F does not depend on the common width bp = bs = bi of the structures (figure 4,5,6). This point is interesting and facilitates the technological realization of these structures since it limits the difficulties of their deep and straight engraving. These fixed electric and ionic charges Q_F , inside the piezoelectric bridge, have opposite signs and induce an electric field that attract from the mass and on the two metallized faces of this bridge , mobile charges of opposite signs.

The mobile charges, for example on face 2 (Figure 4,5), of the faces of the bridge <u>activate the insulating gates</u> of the <u>enriched transistors</u> Thin Film Transistor Metal Oxide Semiconductor T.F.T. M.O.S, N and P in parallel of switch n°1 (Figure 2)[10]. It generates on these transistors a gate voltage V_G with the expression $V_g = \frac{Q_F}{c_{ox}}$ (Eq.3). With, Cox the capacity of the grid's transistors $C_{ox} = \frac{\varepsilon_0 \varepsilon_{ox}}{t_{ox}} L_T W_T$ (Eq.4) and ε_0 the permittivity of vacuum, ε_{ox} the relative permittivity

of silicon oxide , L $_{\tau}$, W $_{\tau}$, tox the length, width and thickness of the grid of the TFT MOS . The mobile charges of the other face 1 (Figure 4,5) of the bridge supply the sources of the T.F.T. M.O.S. N and P and can circulate to homogenize on a so-called Coulomb electrode, if the threshold voltage of the switch n°1 is exceeded. Before closing switch n°1, this Coulomb electrode was grounded by closing switch n°2, consisting of N and P M.O.S. T.F.T 's in depletion and in series. (Figure 3). It is important to note that:

The threshold voltage values of these switches are V_{T1} for switch n°1 and V_{T2} for switch n°2, and that $|V_{T1}|$ very slightly above $|V_{T2}|$ with some tens of millivolts

If the voltage on the insulating gates of the MOS TFTs is above their threshold voltage then: Switch n°1, changes from OFF to ON but conversely switch n°2 changes from ON to OFF (Figure 1)

Description of Switches n°1 or n°2 and Autonomous Electronic Switches Electronic Description

These indispensable switches are made with:

Circuit n°1 (figure 2): with T.F.T. MOS P and MOS N transistors <u>enriched</u> and in <u>parallel</u>: Threshold voltage V_{TNE} and V_{TPE} Circuit n° 2 (figure 3): with T.F.T. MOS P and MOS N transistors in <u>depletion</u> and in <u>series</u>: Threshold voltage V_{TND} and V_{TPD}

An important point is that the threshold voltage values of these transistors are positioned as Figure 1.



Figure 1: Distribution of the Threshold Voltages of Enriched and Depleted N and P MOS Switches.

We have : $V_{TPE} < V_{TND} < 0 < V_{TPD} < V_{TNE}$. For the functioning symmetry $|V_{TPE}|$ can equal $|V_{TNE}|$ and $|V_{TPD}|$ can equal $|V_{TND}|$. Consequently, as $|V_{TND}| < |V_{TPE}|$ and $|V_{TPD}| < |V_{TN}E|$, and with a difference of their values of just some tens of millivolts, circuit switch n° 2 commute, then is open or closed <u>just before</u> circuit switch n° 1 switches respectively from closed or open (see figure n° 1, 2,3, 4, 5, 6, 18).

Circuit n°1: Switch n° 1

Switch n°1 consists -with their threshold V_{TNE} or V_{TPE} voltage- of <u>enriched N type TFT MOS</u>, in parallel with an enriched <u>P type TFT MOS</u> (figure 1,2), as positioned in figure 2. [11].



The common gates voltage of these enriched T.F.T. MOS N and P in parallel of switch $n^{\circ}1$ (figure 2), are controlled by the free charges appearing on face $n^{\circ}2$ of the piezoelectric bridge. The N and P sources of these T.F.T. MOS are connected to face $n^{\circ}1$ of the bridge and the drains Coulomb's electrode. (Figure 4,5).

Figure 2: Switch n°1

The switch n°1 is make with two types of enriched MOSPE or MOSNE transistors in parallel, to avoid the exact nature (holes or electrons) of the mobile electric charges appearing on the metal face n°1 of the piezoelectric bridge. Preferably, their threshold voltages are the same in absolute value $|V_{TNE}| = |V_{TPE}|$. The input of the R.L.C circuit is connected in series between the return Coulomb electrode and the ground, the autonomous electronic n°3 in parallel (figure 4,5). This return Coulomb electrode is itself grounded via switch n°2

Circuit 2: Switches n°2



Figure 3: Switch n°2

Switch n°2, consists of a P type depletion T.F.T. MOSPD in series with an N type MOSND depletion (see figure 1,3,5). The common gates of these MOS switches are controlled by the free charges appearing on face n°2 of the piezoelectric bridge. (figure 1,4,5). The input of switch n°2 is connected to the Coulomb electrode, and its output to the RLC circuit, then to ground. Preferably, their threshold voltages are the same in absolute value $|V_{TND}| = |V_{TPD}|$. The values of $|V_{TND}| \approx |V_{TPD}|$ are lower but very close (down than 10 %) of $|V_{TNE}| \approx |V_{TPE}|$

Schematic and Comportment of the MEMS

Thus, when it is effective (switch n°1 closed), the Coulomb return force FCO is (figure 4,5,6)

$$F_{CO} = \frac{Q_F^2}{4 \pi \varepsilon_0 \varepsilon_r} \left(\frac{1}{z_r + z_0 - z_s}\right)^2 = \left[\frac{d_{31} l_p}{a_p} S_s \frac{\pi^2 c h}{240} \left(\frac{1}{z_s^4} - \frac{1}{z_0^4}\right)\right]^2 \left(\frac{1}{8 \pi \varepsilon_0 \varepsilon_r}\right) \left(\frac{1}{z_r + z_0 - z_s}\right)^2 (\text{Eq. 5})$$

We note that F_{co} is in $1/z_s^{10}$, with z_s = distance (time dependent) between Casimir electrodes, and z_0 = initial distance between Casimir electrodes (without any electric's charges). The schematic of the sensor part of this MEMS is shown in figures (4,5). The perpetual, isotropic and timeless Casimir F_{CA} force, resulting from quantum vacuum fluctuations, causes the deformation of a microscopic piezoelectric bridge embedded in a silicon wafer.







Figure 5: General Configuration of the Device: MOS Grid Connections (Face 2 of the Piezoelectric Bridge: Red), Source Connections (Face 1 of the Piezoelectric Bridge: Green)

We remark that the Casimir force FCA appearing between the reflector electrodes (green) is applied to the piezoelectric bridge (blue) via a metallic digit (green)

When the switch n°1 is open, the mobiles charges of face n°1 don't move and keep on this face n°1. When the switch n°1 is closed and switch n°2 is open, the free moving electric charges must homogenize between the metallic film of face n°1 and the metallic film of Coulombs electrode (Figure 4,5). If the area of Face 1 of the piezoelectric bridge and the area of the electrode Coulomb are equal, then the charge on this electrode is $Q_p/2$. Then, as the electrical nature of mobiles charges of faces n°1 and n°2 are opposite, Coulomb's force F_{co} must appear between these two metallic electrodes. The threshold voltages of the transistors of switch n°1, technologically predetermined, impose the intensity of Coulomb's forces, which can be much greater than the force of Casimir F_{cA} . The Coulomb force's lifespan is ephemeral, and its dissipated energy is determined by the threshold voltages of switch n°2, when it is closed to ground (Figure 1,3,4,5,6).

The resulting force $F_{co} - F_{cA}$, applied to the center of the piezoelectric bridge, changes direction or is zero. The piezoelectric and elastic bridge having no force to keep it deformed, necessarily returns (by the stored deformation energy + the kinetic energy) to its initial position, therefore without any deformation or electrical charges. This ephemeral Coulomb force suppresses the collapse of the two very close electrodes of the Casimir reflector and reduces, then cancels the deformation of the piezoelectric bridge, and thus its electric charges. The structure returns to its initial state and is again deformed by the timeless and isotope Casimir force F_{cA} , which always exists. (Figure 6)



Figure 6: Axes, Forces, Casimir's Electrodes

This cycle reproduces itself and the system vibrates (Figure 8,9,10), with the vacuum energy transmitted by the F_{CA} force, as a continuous drive source for the deformation of the piezoelectric bridge and with the self-built Coulomb force F_{CO} , superior and opposed to F_{CA} as the counter-reaction force. At each cycle, the automatic switching of the integrated switches of circuits n°1 and n°2 (Figure 1,2,3,4,5,6) distributes differently the mobile electrical charges located on face n°1 of the bridge.

Notice that initially, the Coulomb's electrode was grounded by the automatically closing of the switch n°2 (Figure 1,3)

Calculation of the Behaviour of the Structure

Let us calculate the evolution in time of the deflection of the piezoelectric bridge due to the Casimir's force which is applied between the two electrodes separated by an initial distance z_0 (figure 5). We use the theorem of angular momentum for this vibrating structure.(Eq. 6)

$$\overrightarrow{\sigma^{S}_{Ax,y,z}}(Structure) = \overrightarrow{\mathrm{IS}_{A,x,y,z}} \overrightarrow{\theta^{S}_{A,x,y,z}} (Eq. 6)$$

With σ^{s}_{Axyz} the angular momentum vector of the structure, I^{s}_{Axyz} the inertia matrix of the total structure with respect to the reference (A, x,y,z) and θ^{s}_{Axyz} the rotation vector of the piezoelectric bridge with respect to the axis Ay with *a* the low angle of rotation along the y axis of the piezoelectric bridge



Figure 7: Piezoelectric Bridge Cutting Reactions and Bending Moment, Deflection

We have
$$\xrightarrow{\theta^s_A} = \begin{pmatrix} 0 \\ d\alpha/dt \\ 0 \end{pmatrix}$$
 with $d\alpha/dt \approx \frac{2}{l_p} \frac{dz}{dt}$ because $\sin(\alpha) = \sin\left(\frac{2z_s}{l_p}\right) \approx \frac{2z_s}{l_p}$ as $z \ll l_p$

Let (Gp, x, y, z), (Gi, x, y, z), (Gs, x, y, z) be the barycentric points respectively of the piezoelectric bridge, of the connecting metal finger and of the metal block constituting the mobile sole of the Casimir reflector. We have (figure 4,5):

$$\xrightarrow{I}_{AG_{P,x,y,z}} = \frac{1}{2} \begin{pmatrix} l_P \\ b_P \\ a_P \end{pmatrix} \xrightarrow{AG_{I,x,y,z}} = \frac{1}{2} \begin{pmatrix} l_P + l_i \\ b_P + b_i \\ a_F + a_i \end{pmatrix} \xrightarrow{AG_{S,x,y,z}} = \frac{1}{2} \begin{pmatrix} l_P + l_i + l_S \\ b_P + b_i + b_S \\ a_P + a_i + a_S \end{pmatrix}$$

The inertia matrix of the bridge, in the frame of reference (Gp, x, y, z) is:

 $\mathbf{I}_{GP}^{P} = \frac{m_{\rho}}{12} \begin{pmatrix} a^{2}_{\rho} + \mathbf{b}^{2}_{P} & 0 & 0 \\ & l^{2}_{\rho} + \mathbf{b}^{2}_{P} & 0 \\ 0 & 0 & a^{2}_{\rho} + l^{2}_{P} \end{pmatrix}$

Taking Huygens' theorem into account, this inertia matrix becomes

$$\mathbf{I}^{\mathbf{P}}_{\mathbf{A},\mathbf{x},\mathbf{y},\mathbf{z}} = m_{P} \begin{pmatrix} \frac{a^{2}_{p} + b^{2}_{p}}{3} & -\frac{l_{p}b_{p}}{4} & -\frac{l_{p}a_{p}}{4} \\ -\frac{l_{p}b_{p}}{4} & \frac{a^{2}_{p} + l^{2}_{p}}{3} & -\frac{a_{p}b_{p}}{4} \\ -\frac{l_{p}ba}{4} & -\frac{a_{p}b_{p}}{4} & \frac{l^{2}_{p} + b^{2}_{p}}{3} \end{pmatrix} (\text{Eq (7)})$$

With the same reasoning we can calculate the inertia matrix of the finger $I^{I}_{A, x, y, z'}$ and the inertia matrix of the reflector $I^{c}_{A, x, y, z}$ in the frame of reference (A, x, y, z),

$$\mathbf{I}_{A,x,y,z}^{l} = \frac{m_{i}}{12} \begin{pmatrix} a^{2}_{i} + b^{2}_{i} & 0 & 0 \\ 0 & a^{2}_{i} + l^{2}_{i} & 0 \\ 0 & 0 & l^{2}_{i} + b^{2}_{i} \end{pmatrix} + m_{i} \begin{pmatrix} \frac{(b_{p}+b_{i})^{2} + (a_{p}+a_{i})^{2}}{4} & -\frac{(b_{p}+b_{i})(l_{p}+l_{i})}{4} & -\frac{(b_{p}+b_{i})^{2} + (a_{p}+a_{i})^{2}}{4} \\ -\frac{(b_{p}+b_{i})(l_{p}+l_{i})}{4} & -\frac{(b_{p}+b_{i})^{2} + (a_{p}+a_{i})^{2}}{4} & -\frac{(b_{p}+b_{i})^{2} + (l_{p}+l_{i})^{2}}{4} \end{pmatrix} (\mathbf{Eq. (8)})$$

$$\mathbf{I}_{A,x,y,z}^{c} = \frac{m_{s}}{12} \begin{pmatrix} a^{2}_{s} + b^{2}_{s} & 0 & 0 \\ 0 & a^{2}_{s} + l^{2}_{s} & 0 & 0 \\ 0 & 0 & l^{2}_{s} + b^{2}_{s} \end{pmatrix} + m_{s} \begin{pmatrix} \frac{(b_{p}+b_{i})^{2} + (a_{p}+a_{i})^{2}}{4} & -\frac{(b_{p}+b_{i})^{2} + (l_{p}+l_{i}+l_{s})}{4} \end{pmatrix} \\ -\frac{(l_{p}+l_{i}+l_{s})(b_{p}+b_{i}+b_{s})}{4} & -\frac{(l_{p}+l_{i}+l_{s})(b_{p}+b_{i}+b_{s})}{4} & -\frac{(l_{p}+l_{i}+l_{s})(b_{p}+b_{i}+b_{s})}{4} \end{pmatrix} \\ -\frac{(l_{p}+l_{i}+l_{s})(b_{p}+b_{i}+b_{s})}{4} & -\frac{(l_{p}+l_{i}+l_{s})^{2} + (a_{p}+a_{i}+a_{s})^{2}}{4} & -\frac{(l_{p}+l_{i}+l_{s})^{2} + (a_{p}+a_{i}+a_{s})^{2}}{4} & -\frac{(l_{p}+l_{i}+l_{s})^{2} + (a_{p}+a_{i}+a_{s})^{2}}{4} & -\frac{(l_{p}+l_{i}+l_{s})(b_{p}+b_{i}+b_{s})}{4} & -\frac{(l_{p}+l_{i}+l_{s})(b_{p}+b_{i}+b_{s})}{4} & -\frac{(l_{p}+l_{i}+l_{s})(b_{p}+a_{i}+a_{s})^{2}}{4} & -\frac{(l_{p}+l_{i}+l_{s})(b_{p}+a_{i}+a_{s})^{2}}{4} & -\frac{(l_{p}+l_{i}+l_{s})(b_{p}+a_{i}+a_{s})^{2}}{4} & -\frac{(l_{p}+l_{i}+l_{s})(b_{p}+a_{i}+a_{s})^{2}}{4} & -\frac{(l_{p}+l_{i}+l_{s})(b_{p}+a_{i}+a_{s})^{2}}{4} & -\frac{(l_{p}+l_{i}+l_{s})(b_{p}+a_{i}+a_{s})}{4} & -\frac{(l_{p}+l_{i}+l_{s})(b_{p}+a_{i}+a_{s})^{2}}{4} & -\frac{(l_{p}+l_{i}+l_{s})(b_{p}+a_{i}+a_{s})^{2}}{4} & -\frac{(l_{p}+l_{s}+l_{s}+a_{s})^{2}}{4} & -\frac{(l_{p}+l_{s}+l_{s}+a_{s})^{2}}{4} & -\frac{(l_{p}+l_{s}+l_{s}+a_{s})}{4} & -\frac{(l_{p}+l_{s}+l_{s}+a_{s})^{2}}{4} & -\frac$$

The total inertia of the structure becomes in the reference (A, x, y, z) is : $I_{A,x,y,z}^{s} = I_{A,x,y,z}^{p} + I_{A,x,y,z}^{I} + I_{A,x,y,z}^{c} + I_{A,x,y,z}^{c} + I_{A,x,y,z}^{c}$ with A at the edge of the recessed piezoelectric bridge .The angular momentum theorem applied to the whole structure gives :

$$\frac{\overrightarrow{d(\sigma^{S}_{A,x,y,z})}}{dt} \stackrel{\longrightarrow}{=} I^{S}_{A,x,y,z} \quad \overrightarrow{\frac{d\theta^{s}_{A}}{dt}} \quad \Rightarrow \quad \overrightarrow{I^{S}_{A,x,y,z}} \quad \frac{2}{l_{p}} \begin{pmatrix} 0\\ \frac{d^{2}z}{dt^{2}}\\ 0 \end{pmatrix} = \sum_{A} \overrightarrow{Moments of the structure} = \operatorname{Eq.}(10)$$
$$= \overrightarrow{M_{A}} + \overrightarrow{M_{B}} + \overrightarrow{F_{CA}} \wedge \begin{pmatrix} l_{p}/2\\ 0\\ 0 \end{pmatrix} \text{ with } \overrightarrow{F_{CA}} = \begin{pmatrix} 0\\ 0\\ F_{CA} \end{pmatrix}$$

The structure rotates around the Ay axis, the moments at point A are $M_{AY} = M_{BY} = -F_{CA} \ln /8$, therefore the summation of Moments on the structure relative to the axe Ay = $1/4*\ln * F_{CA}$. Any calculation done; we obtain:

$$\overline{I_{y}^{s}} \frac{2}{l_{p}} \frac{d^{2}z}{dt^{2}} = \frac{l_{p}}{4} F_{CA} = \frac{l_{p}}{4} S_{s} \frac{\pi^{2} \text{ tr} c}{240 z^{4}} \text{ Eq. (11)}$$

with I_{y}^{s} the inertia of the structure relatively to the axe Ay [11].

$$I^{S}_{Y} = \rho_{p} a_{p} b_{p} l_{p} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} + \frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{4} \right) + \rho_{i} a_{i} b_{i} l_{i} \left(\frac{\left(l_{i}^{2} + a_{i}^{2}\right)}{12} + \frac{\left(l_{p} + l_{i}\right)^{2} + \left(a_{p} + a_{i}\right)^{2}}{4} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{j}^{2} + a_{p}^{2}\right)}{12} + \frac{\left(l_{p} + l_{i} + l_{j}\right)^{2} + \left(a_{p} + a_{i}^{2} + a_{j}^{2}\right)}{4} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{j}^{2} + a_{p}^{2}\right)}{12} + \frac{\left(l_{p} + l_{i} + l_{j}\right)^{2} + \left(a_{p} + a_{i}^{2} + a_{j}^{2}\right)}{4} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{j}^{2} + a_{p}^{2}\right)}{12} + \frac{\left(l_{p} + l_{i} + l_{j}^{2}\right)^{2} + \left(a_{p} + a_{i}^{2} + a_{j}^{2}\right)}{4} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} + \frac{\left(l_{p} + l_{i}^{2} + a_{p}^{2}\right)}{4} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} + \frac{\left(l_{p} + l_{i}^{2} + a_{p}^{2}\right)}{4} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} + \frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{4} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} + \frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{4} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} + \frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{4} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} + \frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{4} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} \right) + \rho_{i} a_{j} b_{j} l_{j} \left(\frac{\left(l_{p}^{2} + a_{p}^{2}\right)}{12} \right) + \rho_{$$

With ρ_{p} , ρ_{i} , ρ_{s} , respectively the densities of the piezoelectric bridge, the intermediate finger and the mobile electrode of the Casimir reflector. By equation 6, we obtain the differential equation which makes it possible to calculate the interval between the two electrodes of the Casimir reflector as a function of time during the "descent" phase when the Coulomb forces are not present.

$$\frac{d^{2}z}{dt^{2}} = \frac{l_{p}^{2}}{8 I_{y}^{S}} S_{S} \frac{\pi^{2} \text{tr} c}{240} \frac{1}{z^{4}} = \frac{B}{z^{4}} \text{ with } B = \frac{l_{p}^{2}}{8 I_{y}^{S}} S_{S} \frac{\pi^{2} \text{tr} c}{240} \text{ Eq. 13}.$$

This differential equation unfortunately *does not have a literal solution, and we programmed it on MATLAB* to calculate the duration of this "descent" of free Casimir electrode. This duration depending on the desired value of the coefficient of proportionality $p = F_{co}/F_{ca}$. (See figures chapter 4).

<u>Just at the closing switch n°1</u>, we have $F_{_{CO}} = p F_{_{CA}}$ with p, a coefficient of proportionality defined by the threshold voltages of the MOS interrupters. Just at the end of "descent" and the start of the charge transfer, the total force $F_{_{T}}$ exerted becomes: $F_{_{T}} = F_{_{CA}} - F_{_{CO}} = F_{_{CA}} (1-p)$. The "descent" time of the free Casimir electrode will therefore stop when $F_{_{CO}} = -p F_{_{CA}}$. We can calculate this point z1 where $F_{_{CO}} = p F_{_{CA}}$.

1 / The Casimir force is variable in time, but its equation is (Eq. (1)): $F_{CA} = \frac{d(E_{CA})}{dz} = S(\frac{\pi^2 h c}{240 z_4^4})$ 2 / The mobile

charges transiting from side 1 to the Coulomb electrode through circuit 1 variable also with time (Eq. (2)) are: $Q_{mn} \approx \frac{Q_{mn1}}{2} = \frac{d_{31} F_{CA} l_P}{2 a_P}$ because they have the same area. 3 / The Coulomb force (Eq 5), variable over time, acting in opposition to the Casimir force :

$$F_{CO} = \left(\frac{d_{31}l_p}{a_p}l_s b_s \frac{\pi^2 \mathbf{h} \mathbf{c}}{240} \left(\frac{1}{z_s^4} - \frac{1}{z_0^4}\right)\right)^2 \left(\frac{1}{8 \pi \epsilon_0 \epsilon_r}\right) \left(\frac{1}{z_r + z_0 - z_s}\right)^2 =$$
(Eq. 14)
$$p F_{CA} = p l_s b_s \frac{\pi^2 \mathbf{h} \mathbf{c}}{240} \frac{1}{z_r^4}$$

So, the "descent" of the free Casimir electrode stops when the inter electrode interface z_s is such that:

$$z_{S}^{4}\left(\left(\frac{1}{z_{R}+z_{0}-z_{S}}\right)^{2}\left(\frac{1}{z_{s}^{4}}-\frac{1}{z_{0}^{4}}\right)^{2}\right)=\frac{1920\ p\ e_{0}\ e_{r}}{\pi\ \text{tr}\ c\ S_{S}}\left(\frac{a_{P}}{d_{31}\ l_{P}}\right)^{2}(\text{Eq. (15) See Figure (18)})$$

This programmable equation gives the time t_d of the "descent" of the structure submitted to the Casimir force and:

• depend on the coefficient of proportionality p:
$$F_T = (1-p) F_{CA} \Rightarrow (1-p) S_S \frac{\pi + \pi c}{240 z_{sm}^4} < 0$$
 if $p > 1$

• is calculable and will stop when the inter-electrode interface z_s has a value z_1 satisfying equation (15).

During all the phase where $0 < VT_{ND} < V_{GRIDS} \le VT_{NE}$, or $VT_{PE} \le V_{GRID}S < VT_{ND} < 0$. The total force, variable over time and exerted at the center of the piezoelectric bridge, becomes:

$$F_{T} = F_{CA} - F_{CO} = S_{S} \frac{\pi^{2} \text{ tr} c}{240 z_{S}^{4}} - \frac{1}{2} \left[\frac{S_{S} \pi^{2} \text{ tr} c}{240} \left(\frac{1}{z_{s}^{4}} - \frac{1}{z_{0}^{4}} \right) \left(\frac{d_{31}l_{P}}{a_{P}} \right) \right]^{2} \left(\frac{1}{4 \pi e_{0} e_{r}} \right) \left(\frac{1}{z_{r} + z_{0} - z_{s}} \right)^{2} \text{ Eq. (15)} .$$

The piezoelectric bridge subjected to this new force F_T rises towards a position where the Coulomb's F_{co} disappears at the point z_2 (figure xx), because the switch n° 2 closed to ground, via a R.L.C. circuit (figure 4,5). When F_{co} disappears, the whole moving structure (Casimir reflector electrode + finger + piezoelectric bridge) with an important masse M_t , acquires a kinetic energy E_c with $E_c = \frac{1}{2} M_t V_t^2$ and $M_t = \rho_P (a_p b_p l_p) + \rho_i (a_i b_i l_i) + \rho_s (a_s b_s l_s)$, Vt= speed of the mobile structures, ρ_p , ρ_p , ρ_s , $a_p b_p l_p$, $a_i b_i l_i$, $a_s b_s l_s$, respectively the volumic mass and volume of the piezoelectric bridge, finger and Casimir electrode.

Let us calculate an approximation of the duration of this "rise" of the mobile electrode Casimir's reflector + finger + piezoelectric bridge, triggered when $F_{co} = p F_{cA}$. This time is approximated because when the Coulomb force F_{co} stop (because the closing of the switch n° 2 to ground at the point z_2 between z_1 and the initial point z_0 , Figure 6), the mobile structure loses its kinetic energy E_c plus its deformation energy with the braking force provided by the Casimir force. We approximate this return time by saying that point z_2 of the loss of the Coulomb force occurs at the initial point z_0 . In these conditions, to know the time taken by the structure to "go back" to its neutral position, we must solve the following differential equation:

$$\frac{d^{2}z}{dt^{2}} = \frac{l_{p}^{2}}{8I_{s}^{Y}} \left(F_{CA} - F_{CO}\right) = \frac{l_{p}^{2}}{8I_{s}^{Y}} \left(\left(l_{s}b_{s}\frac{\pi^{2} \mathbf{h} \mathbf{c}}{240 z_{s}^{4}}\right) - \frac{1}{2} \left[l_{s}b_{s}\frac{\pi^{2} \mathbf{h} \mathbf{c}}{240} \left(\frac{d_{31}l_{p}}{a_{p}}\right) \left(\frac{1}{z_{s}^{4}} - \frac{1}{z_{0}^{4}}\right)\right]^{2} \right] \left(\frac{1}{4\pi\varepsilon_{0}\varepsilon_{r}}\right) \left(\frac{1}{z_{r} + z_{0} - z_{s}}\right)^{2} \mathbf{Eq.(16)}$$

This differential equation (18) has no analytical solution and can only be solved numerically.

We programmed it on MATLAB. In these MATLAB simulations we considered that the metal of the electrodes and metal block was oxidized over a thickness allowing to have an interface between Casimir electrodes of 200 A ° which modifies the mass and the inertia of the vibrating structure (See chapter 5). It turns out that the choice of aluminium as the metal deposited on these electrodes is preferable given:

• The ratio between the thickness of the metal oxide obtained and of the metal attacked by the thermal oxidation (see chapter 6)

• Its low density increase and optimise the vibration frequency of the structure by minimising the inertia of the Casimir reflector and the parallelepiped block that transfers the Casimir force.

The mass $M_{structure}$ of the vibrating structure is then: $M_{STRUCTURE} = d_{pm}(a_s b_s I_s + a_i b_i I_i) + 2 d_{om} z_{of}(a_{s0} b_{s0} + b_{s0} I_{s0} + a_{s0} I_{s0}) + d_p(a_p b_p I_p)$. With dpm the density of the metal, a_s, b_s, I_s the geometries of the final metal part of the Casimir electrode sole, d_{om} the density of the metal oxide, a_{s0}, b_{s0}, I_s the geometries of the oxidized parts around the 6 faces of the metal block, d_p the density of the piezoelectric parallelepiped (see figure 4,5):

Simulation of Devices with Different Piezoelectric Bridge

We present below the results of the MATLAB simulations carried out by numerically calculating the differential equations

(11) and (13). These numerical calculations give the vibration frequency of the structure which, as we will see, vibrates at a frequency lower than its first resonant frequency (IV). This vibration frequency depends on the characteristics of the structure (Nature of material, geometric dimensions, coefficient of proportionality $p = F_{co} / F_{cA} \dots$)). The metal used for the Casimir reflector block is Aluminium with a density of 2.7 g cm⁻³

Piezoelectric Materials for the Piezoelectric Bridge

To increase the density of electric charges at the terminals, piezoelectric material PMN-PT can be used. It can be deposited by RF-magnetron sputtering with a composition, for example: PMN-PT= (1-x) \mathbf{P}_{b} (1/3 \mathbf{M}_{g} - 2/3 \mathbf{N}_{b}) O_{3-} x $\mathbf{P}_{b}\mathbf{T}_{i}O_{3}$; with piezoelectric coefficient d ₃₁ = 1450 .10⁻¹² C / (kg .m .s⁻²) and a Young's modulus Ep = 150 .10⁹ Kg M⁻¹ T⁻².

With MATLAB simulation, and for an interval between Casimir electrode $z_0 = 200$ Angstroms, we obtain the evolution over time of the Casimir and Coulomb forces as well as the F_{co} / F_{cA} ratio of figures 8 to 22 below. For a ratio $p = F_{co}$ / F_{cA} of 1000, the maximum current I delivered by the vibrating structure, the threshold voltage of the MOSE and the vibration frequency of the structure are respectively: $I=1.2 \ 10^{-4} A$, Vt = 3.2 V and 957000 Hertz

Evolution of the Casimir Interface as a Function of Time During two Periods: PMN-PT

The F_{co} / F_{cA} ratio = 10000 induces a period of 3.85 10⁻⁶ s and a rise time of 21.3 10⁻⁹ s with a deflection of the bridge of 105 A °. The structure vibrates at 259.7 kHz. Due to inertia, at the rise sequence, the structure exceeds the initial 200 A ° by 20 A ° (Figure 28).



Figure 8: Plot of the Evolution of the Casimir Inter-Electrode Interval as a Function of Time Over Two Periods and an Fco / Fca Ratio = 10000: Casimir Inter-Electrode Interface = 200

A ratio F_{co} / F_{cA} = 1000 induces a period of 2.96 10⁻⁶ s and a rise time of 44.5 10⁻⁹ s with a deflection of the bridge of 50 A ° The structure vibrates at 337.8 kHz: (figure 29). For this ratio of 10000 we notice a vibration amplitude of 50A °, a period of 2.96 10⁻⁶ s, with the faster rise of the mobile electrode producing a slight rebound of 5A, because of the inertia of the structure.



Figure 9: Plot of the Evolution of the Casimir Inter-Electrode Interval as a Function of Time Over Two Periods and Fco / Fca Ratio = 1000: Casimir Inter-Electrode Interface = 200 A°

For the ratio F_{CO} / F_{CA} = 2 (figure 30) a vibration amplitude of just 0.27 A ° and a period of 1.8610⁻⁷ s is obtained This low deformation of the PMN-PT piezoelectric bridge is mainly due to the extremely high piezoelectric coefficient d₃₁ of 1450 (pC/N) of PMN-PT compared to 120 (pC/N) for PZT.

We observe the weak overshoot of the initial interface.

PMN-PT MATERIAL

INTERVAL BETWEEN CASIMIR ELECTRODES AS A FUNCTION OF TIME



Figure 10: Plot of the Evolution of the Casimir Inter-Electrode Interval as a Function of Time Over Two Periods and a Ratio Fco / Fca = 2. Casimir Inter-Electrode Interface = 200 A

Evolution of the Forces of Casimir and Coulomb: PMN-PT

We obtain:

- The evolution of the Casimir and Coulomb forces as a function
 - of the inter-electrode interface (figure 31) and
 - over time (figure 32)
- The FCO / FCA ratio as a function of time for an entire period (figures 33).



Figure 11: Materials = PMN-PT: Coulomb Figure 12: Materials = PMN-PT: Coulomb and Casimir Force as a Function of the Interand Casimir Force as a Function of Time. Start Electrode Interface. Start Interface = 200A ° Interface = 200A °



Figure 12: Materials = PMN-PT: Coulomb Figure 12: Materials = PMN-PT: Coulomb and Casimir Force as a Function of Time. Start Interface = 200A °

It is observed (Figure. 33) that the Coulomb return force is less important for an initial inter-electrode gap $z_r = 400A^{\circ}$ than for $zr = 200A^{\circ}$



Figure 13: Materials = PMN-PT: Coulomb Force for $z_r = 200 \text{ A}^\circ$ (Blue) and $z_r = 400 \text{ A}^\circ$ (Red) and Casimir Force (Yellow, z0 = 200 A°) as a Function of the Inter-Electrode Interface Starting Interface = 200 A



Figure 14: Materials = PMN-PT: Ratio $p = F_{co} / F_{ca}$ as a Function of Time, During a Period of Vibration. Start interface = 200A °, Maximum ratio chosen = 450

The break circuits n°1 triggered at time $t = 2.44 \ 10^{-6}$ s suddenly induce a rise of the mobile electrode, therefore a sudden decrease in electric charges and grids voltages. We observe the gradual evolution towards the chosen ratio of 450 and then the sudden drop in this ratio as the electrodes regain their initial position (Figure. (34)).

Threshold Voltage According to the Desired Ratio F_{co} / F_{ca}: PMN-PT



Figure 15: Materials = PMN-PT: Threshold Voltage of the Enriched or Depleted MOS According to the F_{co} / F_{ca} Ratio. Start Interface = 200A °

It can be seen (Figure. 15) that we must increase the threshold voltage of the TFT MOS of switch n°1 up to 3.5V if we desire to obtain a ratio $F_{_{CO}}/F_{_{CA}}$ of 1000.

Vibration Frequency as A Function of the F_{co} / F_{cA} Ratio and Peak Current as a Function of the Initial Casimir Interval Chosen: PMN-PT.

Note (figure 16), that for an initial interface $z_0 = 200 \text{ A}^\circ$, and for a ratio $F_{_{CO}} / F_{_{CA}} = 2$, the maximum vibration frequency of the structure is 3.50 MHz. It falls to 750 kHz for a ratio of 1000. These frequencies are still lower than the first resonance of the structure, which is of the order of 7.94 Megahertz. This vibration frequency of the Casimir structure approaches that of the first resonance for weaker interfaces below 200 A°.

For a ratio F_{co} / F_{cA} = 500, the maximum current delivered by the structure falls as a function of an increase in the initial Casimir interval (Figure 17).

It seems that the piezoelectric material PMN-PT coupled with a conductor like aluminium is an interesting couple for our vacuum energy extraction structure.



Figure 16 : Materials = PMN-PT: Vibration Frequency as a Function of the F_{CO} / F_{CA} Ratio. Start Interface = 200A ° Start Interface = 200A



Figure 17: Materials = PMN-PT: Current Peak Across the 2 . 10-4 H Inductance as a Function of the Starting Interval Between Casimir Electrodes. Start Interface = 200A

Mems Energy Balance

In this part, we will try to make a detailed and exhaustive assessment of the behavior of the MEMS during one vibration. Firstly, we will focus on the first half of this vibration, which we will call the "go" phase. Secondly, we will focus on the second half of the vibration, which is to say the "return" phase. Let us recall that, the piezoelectric bridge is perfectly elastic, which implies, as with any elastic structure, that the energy expended by a mechanical deformation of the positions from 0 to 1 is integrally restored when returning. The conditions of use of the piezoelectric bridge (vibrations amplitude) are in the purely elastic domain and we never enter in the domain of plasticity.

In the following we propose to put into equation the energy balance of «go» then in "return "steps .

 $0 < VT_{PD} < VT_{NE'}$ and $VT_{PE} < VT_{ND} < 0$ and $F_{co} / F_{CA} < p$. With p the chosen amplification F_{co} / F_{CA} . We note V_{T1} = abs (VT_{NE} or VT_{PE}) and V_{T2} = abs (VT_{ND} or VT_{PD}), and call VG the voltage due to the mobiles charge on the face 2 of the piezoelectric bridge and appearing on the gate of all the TFT MOS transistors "[11]".

MEMS Energy Balance During the Phase "go" from z_0 **to** z_1 • 0 < V_G < abs (V_{T2}) < abs(V_{T1}). and F_{c0} / F_{cA} < p: switch n°1 OFF, Switch n°2 ON. (Figure 1) At the start, in the beginning conditions of the "go" phase, we have very small deformations applied to the piezoelectric bridge. Consequently, very small electrical charges are present on it, so the electrical voltages V_G on the grid of the enriched and parallel TFT MOS N and P of switch N°1 is lower than their threshold voltage V_{T1} . This witch n°1 is open and in the OFF position. On the other hand, as $V_{G} < V_{T2}$, switch N°2 consisting of two TFT MOS N and P in series, operating in depletion mode is closed and in the ON position to ground. In these conditions the so-called Coulomb electrode is to the ground, thus eliminating the Coulomb force F_{co} .

• 0 < abs (V_{T2}) < V_{G} < abs (V_{T1}). and F_{co} / F_{CA} < p: switch n°1 OFF, Switch n°2 OFF. (Figure 1) No moving electric charge appears on the return side of the Coulomb electrode, which is connected to ground by switch 2, which is ON, and isolated from the piezoelectric bridge by switch 1, which is OFF. The Casimir force begins to deform the piezoelectric bridge more significantly. Consequently, the mobiles charge on face 1 and 2 of the piezoelectric bridge therefore the voltage V_G on the gates of transistors of switch n° 1 and n° 2 increases. This voltage VG still lower than the threshold voltage V_{T1} , exceeds now V_{T2} of switch n°2 which opens and switches OFF.

The structure being assumed to be perfectly elastic and the amplitudes of the vibrations being extremely low, we will see that the mechanical energy losses by an increase of temperature in the device are negligible.

 Note also that the mobile parallelepiped metal electrodes of the Casimir electrodes remain parallel to each other and that the mobile metal Casimir electrode does not deform. It simply transmits its movement to the piezoelectric bridge which deforms but therefore does not heat up. (Figure 4,5)

•The expulsion of entropy ΔS from the vibrating structure of Casimir is transmitted to the piezoelectric bridge. It causes an extremely slight increase ΔT in its temperature and expels this heat to the outside. Let us calculate an order of this magnitude ΔT . We note ΔQ_{vib} the heat transmitted by the vibrations of the piezoelectric bridge. In first approximation, we can use the well-known formula $\Delta Q_{vib} = \Delta S$. ΔT , with ΔS = entropy variation (J °K⁻¹) and T = temperature variation (° K)

However, we know that: $\Delta Q_{vib} = \frac{M_{Bridge} [2 \pi f_{vib}]^2}{2} z_1^2$ Eq. (17) With: f_{vib} = Vibration frequencies of the piezoelectric bridge, M_{Bridge} = mass of this bridge, which is the only one to deform because the Casimir electrodes are simply in translations. We note z, the maximum deflection of the bridge (Figure 6) "[10]". This heat expended at the level of the piezoelectric bridge causes its temperature to increase.

As a first approximation we can say: $\Delta Q_{vib} = M_{Structure}$. $C_{piezo} \Delta T$. With: $C_{piezo} = Specific heat capacity of the piezoelectric bridge (J Kg⁻¹ °K⁻¹), <math>\Delta T = Temperature variation (°K)$.

Consequently $\Delta T = \frac{2 [\pi f_{vib}]^2}{C_{nicco}} z_1^2$ = Temperature variation of the bridge. Eq. (18)

For example, for a PMN-PT piezoelectric film: $C_{piezo} = C_{PMN-PT} = 310$ (J Kg⁻¹ °K⁻¹), $f_{vib} \approx 10^6$ Hz, ze 100*10⁻¹⁰ m, we then obtain: $\Delta T \approx 10^{-3}$ °K. The expulsion of entropy from the vibrating Casimir Electrode is negligible. We note that simply half of this expended heat occurs in the "go", the second part occurs in the "return" phases of the vibration.During a cycle from z_0 to z_1 , to deform the elastic piezoelectric bridge during the displacement "go" of the vibration, the quantum energy $E_{CASIMIR}$, given by the quantum vacuum, is used for four different energies:

• The mechanical energy for the deformation of the elastic bridge: W_{DEFCA}

 The energy to create the fixed Q_F charges in this piezoelectric structure : W_{BRIDGE}
 The energy for the simple displacement of the point of application of the Casimir force in the middle of the bridge : **WCASIMIR**

• The expulsion of entropy $\Delta S/2$ energy, expended in heat due to the friction of the atoms in the half of the vibration of the bridge heat : Q_{vib} /2

We can write that to deform the piezoelectric bridge from the start position z_0 to the position z_1 :

$\mathbf{E}_{\text{CASIMIR1}} = \mathbf{W}_{\text{DEFCA1}} + \mathbf{W}_{\text{BRIDGE1}} + \mathbf{W}_{\text{CASIMIR1}} + \mathbf{Q}_{\text{vib}} / 2, \text{ (Eq 8).}$

This quantum vacuum energy $E_{CASIMIR1}$ is bigger than the simple translation energy $W_{CASIMIR1}$. The energies WDEFCA and WBRIDGE are store in the deformed piezoelectric bridge as a potential energy.

The Translation Energy of the Casimir Force is:

 $W_{\text{CASIMIR1}} = \int_{z_0}^{z_1} F_{\text{CA}} dz = \int_{z_0}^{z_1} S \frac{\pi^2 + c}{240 z_s^4} dz_s = S\left(\frac{\pi^2 + c}{720}\right) \left[\frac{1}{z_1^3} - \frac{1}{z_0^3}\right]. (\text{Eq 19})$

The $W_{CASIMIR1}$ energy represents the translation of the Casimir force F_{CA} from z_0 to z_1 without considering that this force also deforms an elastic and piezoelectric structure from z_0 to z_1 . Now, let's calculate the deformation energy W_{DEFCA} of the piezoelectric bridge fixed at both ends.

We know that the deformation energy of an elastic system is the energy that accumulates in the solid body during its elastic deformation. Yet, all Material Resistance book says that the deformation energy W_d of an embedded elastic bridge and for a constant force F is : $W_d = \frac{1}{2} z_e F$ with $z_e = z_0 - z_s$, the deflection (arrow) acquired by the elastic bridge subjected to the constant force F. In the case of our piezoelectric bride the force F being the Casimir force, varies in 1/ z^4 , with the distance z.

So, for a differential deflection dz of the bridge under the force F(z) we can write :

$$d(W_d) = 1/2 F(z) dz . \implies W_d = \frac{1}{2} W_{DFCA}(z_s) = \frac{1}{2} S \frac{\pi^2 + c}{240} \int_{z_0}^{z_s} \frac{1}{z^4} dz = \frac{1}{6} \frac{\pi^2 + c}{240} \left[\frac{1}{z_s^3} - \frac{1}{z_0^3} \right] (Eq. 20)$$

This energy W_{DEFCA} is stored in the elastic bridge as a potential energy. The position of the mobile Casimir electrode reaches the limit z_1 when the grid voltage V_G on switch n°1 reaches its threshold voltage V_{T1} . This reached position z_1 is unstable because the Casimir force increases with its position. As a result, the mobile Casimir electrode can collapse. But, when the Casimir electrode is in position z_1 , the switch n°1 switches to ON. The charges present on the metallic face nº1 of the piezoelectric bridge must homogenize with the metallic Coulomb electrode, which was previously grounded by the closing of switch n°2. Note that, when switch n°1 switches, switch n°2 is still open because the voltage of the TFT MOS of switch n°2 are in depletion $V_G > V_{T2}$ (Figure 1,4,5,6).

The energy stored in the bridge through its deformation is in $z_1 W_{DFCA1} = \frac{1}{6} S \frac{\pi^2 + c}{240} \left[\frac{1}{z_1^3} - \frac{1}{z_0^3} \right]$ Eq 21, At position z_2 of the structure, the memorized elastic energy is $W_{DFCA2} = \frac{1}{6} S \frac{\pi^2 + c}{240} \left[\frac{1}{z_2^3} - \frac{1}{z_0^3} \right]$ Eq 22.

We notice that $W_{DEFCA} > 0$ and that the numerical value of W_{DEFCA1} is a little smaller than the expression calculated when $F_{CA}(z_1)$ was constant : Wd= $\frac{1}{2}$ ze* $F_{CA}(z_1)$.

• During the displacement " go " the energy ECASIMIR is also used to generate a potential energy W_{BRIDGE} accumulated in the capacity of this piezoelectric bridge which follows the equation: $d(_{WBRIDGE}) = Q_F d(V_{PIEZO})$ with $V_{PIEZO} = V_{oltage}$ between the two metallic faces of the piezoelectric bridge , with $Q_F = C_{PIEZO} V_{PIEZO} \Rightarrow W_{BRIDGE1} =$ potential energy at the position z_1

$$W_{BRIDGE1} = \int_{0}^{Q_{1}} \frac{Q_{F}}{c_{PIEZO}} d(Q_{F}) = \left[\frac{Q_{F}^{2}}{2 c_{PIEZO}}\right]_{0}^{Q_{1}} = \frac{a_{P}}{2 l_{P}b_{P}\epsilon_{0} \varepsilon_{PIEZO}} \left(\frac{d_{31} l_{p}}{2 a_{P}}\right)^{2} F_{CA}^{2} = \left(\frac{a_{P}}{2 l_{P}b_{P}\epsilon_{0} \varepsilon_{PIEZO}}\right) \left(\frac{d_{31} l_{p} l_{s}b_{s} \pi^{2} c^{\frac{1}{2}}}{480 a_{P}}\right)^{2} \left[\frac{1}{z_{1}^{4}} - \frac{1}{z_{0}^{4}}\right]^{2} \text{Eq. (23)}$$

We notice that $W_{BRIDGE1} > 0$, similarly when the structure reaches position z_2 , the same memorized elastic energy occurs. To get $W_{BRIDGE2}$ for position z_2 of the bridge, we simply swap z_1 for z_2 . In these equations, we use $d(Q_F) = C_{PIEZO} d(V_{PIEZO})$, with $C_{PIEZO} =$ electrical capacity of the piezoelectric bridge, $C_{PIEZO} \frac{\epsilon_0 \epsilon_{PIEZO}}{a_P} b_P l_P$ Eq.24.

We know (Eq2) that the creating fixed charges on this piezoelectric structure is $Q_F = \frac{d_{31}l_P}{q_E} F_{CA}$.

We have $Q_e = -Q_F$ = the accumulated mobile charges, coming from the mass, on the surface of the metallic film. This part W_{BRIDGE} of E_{CASIMIR} is stored in the piezoelectric bridge as potential energy and contributes to the usable energy W_{ELECTRIC} appearing during a cycle.So, during the phase "go" from z_0 to z_1 the total energy coming from the vacuum = E_{CASIMIR} is used:

- to deform the piezoelectric bridge W_{DEFCA},
- to produce the electrical charges as potential energyW_{BRIDGE1}
- Translate the point of application of the Casimir Force $W_{CASIMIR'}$ produce a heat of the structure by the entropic transfer $Q_{vib}^{VID}/2$

We have:

Energy produces by vacuum = $\mathbf{E}_{vacuum} = \mathbf{W}_{dFCA} + \mathbf{W}_{CASIMIR} + \mathbf{W}_{BRIDGE} + \mathbf{Q}_{vib}/2 = \mathbf{W}_{GOING}$ (Eq 25) WDEFCA and WBRIDGE are potential energies that will be used when the elastic bridge returns to its equilibrium position, that is to say without deformation.

MEMS Energy Balance During the "Return" Phase from z_0 to z_1 ", Switch n°1 ON, Switch n°2 OFF: 0 < abs

 $(V_{T2}) < V_G < =$ abs (V_{T1}) . and Ratio $F_{co} / F_{CA} > = p$: (Figure 1) Figure 15 page 10 above, shows the F_{co}/F_{CA} ratio obtained by the choice - defined during the technological realization of the MEMS- of the threshold voltage V_{T1} of switch n°1. Now , the voltage on the grids of switch n°1 exceed its threshold voltage and switch commute ON. The switch n°2 is till OFF, so the Coulomb's electrode is opened . The free charges Q_{m1}, stored on the metal electrodes of face 1(Figure 1,4,5), passing through one of the MOSE transistors, are uniformly distributed on the Coulomb metal electrode of the surface for example $S_{c1} = lp*bp$. If $S_{c1} = S_{p1}$, this metallic Coulomb's electrode therefore has approximately a mobile charge $Q_{mn} S_{c1} / S_{p1} = Q_{mn} / 2$.

This homogenization is obligatory because there is no electric field in a perfect metallic conductor. The free charges Q_m, stored on face 2 and on all the isolated grids TFT MOS don't move. So, grids electrode and return electrode have opposite free charge. (Figure 4,5,15). A Coulomb force F_{co} then appears between these two electrodes during the very short time when switch no. 2 is still open, isolating the Coulomb electrode from the ground. The resulting force $F_{R} = F_{CO}$ - F_{cA} is now applied to the piezoelectric bridge. This force F_{R} , is opposite to the force F_{cA} or null. In presence of this force F_{R} the deformations of the bridge and its electrical charges, so the grids voltage are necessarily reduced.

Since the threshold voltage V_{T_2} of switch n°2 is lower but very close to V_{T_1} (we choice $V_{T_1} - V_{T_2} = 50$ mV), the time duration during which this Coulomb force is exerted is very small (a few nanoseconds).

Very quickly, the switch n°2 commutes from OFF to ON, grounding the Coulomb electrode via an R.L.C. circuit, (Figure 23). The Coulomb force vanishes quickly after its appearance at position z_2 . The values of V_{T2} and V_{T1} impose that z_2 is very close to z_1 . So, the energy $W_{COULOMB} = \int_{z_1}^{z_2} F_{CO} dz$ expended by the Coulomb force remains low, even if this force is several times that of Casimir in intensity.

The time of existence of F_{co} is of the order of a few tens of nanoseconds (figure 1,5). The position z_1 of appearance of this force F_{co} is such that $F_{co} = p F_{ca}$ and is numerically calculated by MATLAB(figure. 18)

$$F_{CO} = pF_{CA} \Rightarrow \frac{Q_F Q_F}{8 \pi \varepsilon_0 \varepsilon_r} \left(\frac{1}{z_r + z_0 - z_s}\right)^2 = \left[\frac{d_{31} l_p}{a_p} S_S \frac{\pi^2 c h}{240} \left(\frac{1}{z_s^4} - \frac{1}{z_0^4}\right)\right]^2 \left(\frac{1}{8 \pi \varepsilon_0 \varepsilon_r}\right) \left(\frac{1}{z_r + z_0 - z_s}\right)^2 = p S \frac{\pi^2 c h}{240 z_s^4}$$
Eq 26

We note that the position z_1 depends on the values of the interface's z_0 of Casimir's electrodes and of Coulomb's electrodes z.



Figure 18: Position of the Mobile Casimir Electrode z1 where the Coulomb Force Occurs : $z_r = z_0 = 200 A^\circ$, Is = 500 μ m, bs = 20 μ m, lp = 50 μ m, bp =20 μ m, ap = 10 μ m

The $F_{R} = F_{CO} - F_{CA}$ force is now applied to the mobile structure. This resulting force is at least zero or has a greater intensity than the Casimir force F_{cA} . It contributes with the energy stored in the elastic bridge to straighten the structure and to give it kinetic energy. This F_{co} force exists as long as switch n°2 has not switched to ground, canceling its existence by the dispersion of charges on the Coulomb electrode.

We describe below the energy dispensed in the cycle of the piezoelectric bridge positions. We hope show that a usable energy W_{ELECTRIC} is possible and not due to any electrical energy applied but by the dissipation of the mobile electric charges to the mass throw the switch n°2 and an R.L.C. circuit.(Figure 21)

There are two phases for this return to from z_1 to z_0 (returning phase): • from z_1 to z_2 where the Coulomb's force F_{co} exist and contribute to straighten the elastic structure and to give it kinetic

energy,

• from z_2 to z_0 where this acquired kinetic energy, and the remaining energy still stored in the structure which will be dissipated by the energy spent by the Casimir force.

Calculation of Energies Between z₁ and z₂

As soon as switch n°1 has switched to homogenize the electric charges between face 1 of the bridge and the Coulomb electrode, the resulting force F_{CO} - F_{CA} straightens this bridge and the electric charges drop. The electric voltage on the grids falls below the threshold voltage of this switch n°1 which commute again very quickly. The energy $W_{COULOMB}$ is write $W_{COULOMB} = W_{FC0} = \int_{z_2}^{z_1} F_{C0} dz = \left\{ S_S \cdot \frac{\pi^2 + c}{240} \cdot \frac{d_{31} l_p}{a_p} \right\}^2 \left(\frac{1}{8 \pi \epsilon_0 \epsilon_r} \right) \cdot \int_{z_2}^{z_1} \left[\left(\frac{1}{z_s^4} - \frac{1}{z_0^4} \right) \left(\frac{1}{z_r + z_0 - z_s} \right) \right]^2 dz_s$ Eq27. This energy

exists only between the very close positions z_1 and z_2 . The literal formulation of WCOULOMB energy is possible but its expression is not convenient because it is too complex. We prefer to calculate by MATLAB its numerical value between the value z_1 and z_2 .

The position z_2 of commutation of switch n°2 is deduced from the chosen threshold value V_{T2} of switch n°2.

We note that we can minimize the value of the energy spent by $W_{COULOMB'}$ by choosing a value of the threshold voltage V_{T2} close but slightly lower than V_{T1} of switch n°1.For example $V_{T2} = V_{T1-} 0.05$ (V). We use MATLAB to find position z_2 of commutation of circuit 2 to cancel the Coulomb's Force $F_{CO'}$ see (Eq 22) and figure 18. We have, at position z_2 of the bridge, the electric charge in the TFT MOS.

$$Q_{2} = \frac{d_{31} l_{p}}{a_{p}} S_{S} \frac{\pi^{2} c h}{240} \left(\frac{1}{z_{2}^{4}} - \frac{1}{z_{0}^{4}} \right) \text{ with } Q_{2} = \text{Cox } V_{T2} \text{ So }, Z_{2} = \frac{1}{\sqrt[4]{\left[\frac{240 a_{p} C_{0X}}{d_{31} l_{p} \pi^{2} c h S_{S}} V_{T2} + \frac{1}{z_{0}^{4}}\right]}} \quad (\text{Eq .28}).$$



Figure 19: Energy of Translation of Casimir Force and Energy of Coulombs 'Force between its Apparition in the Position z, and its Disappearance in Position z,

We present in figure 21 the curve representing the translation energy of the Casimir force as well as the Coulombs force the time when the structure is between the positions z and z, which represents a few nanoseconds.

We can calculate the energy spent in the first part of return of the structure (from z_1 to z_2) Figure 6, by simply calculating the kinetic energy $W_{_{CIN}}$ acquired by the structure when it reaches the position z_2 upon its return. We know that the variation of the kinetic energy $W_{_{CIN}}$ is equal to the sum of all the energies supplied or spent on the moving structure. Thus, as we know the numerical value of all these participants in the variation of this kinetic energy $W_{_{CIN}}$, we can write equation Eq.25 which allows us to calculate $W_{_{CIN}}$ because all the terms of this equation are known.

$$\mathbf{W}_{\text{CIN}} = (\mathbf{W}_{\text{DFCA1}} + \mathbf{W}_{\text{BRIDGE1}}) - (\mathbf{W}_{\text{DFCA2}} + \mathbf{W}_{\text{BRIDGE2}}) + \mathbf{W}_{\text{COULOMB}} - (\mathbf{W}_{\text{CASIMIR1}} - \mathbf{W}_{\text{CASIMIR2}}) \quad (\text{Eq. 29}) \text{ and figure 20}.$$

All the terms of equation are known, so we know now the kinetic energy acquired by all the mobile system in z_1 and know when the Coulomb force disappears. All calculations done, we obtain :

$$W_{CIN} = \frac{1}{6} S \frac{\pi^2 + c}{240} \left(\frac{1}{z_2^3} - \frac{1}{z_1^3} \right) + W_{COULOMB}$$

We know now the kinetic energy acquired in z_1 and know when the Coulomb force disappears.

The structure must now spend this energy which gives it inertia. The braking energy provided by the Casimir force will cancel this kinetic inertia plus that stored in the elastic energy. Let us calculate the final ascent position z_f of the mobile structure. It has an inertia provided by the kinetic energy W_{CIN} , a stored elastic energy WDFCA but is slowed down by the energy provided by the Casimir force

We can write
$$W_{CIN} + \frac{1}{6}S\frac{\pi^2 + c}{240}\left(\frac{1}{z_2^3} - \frac{1}{z_f^3}\right) = \frac{1}{3}S\frac{\pi^2 + c}{240}\left(\frac{1}{z_2^3} - \frac{1}{z_f^3}\right) \implies W_{CIN} = \frac{1}{6}S\frac{\pi^2 + c}{240}\left(\frac{1}{z_2^3} - \frac{1}{z_f^3}\right)$$

We deduce of this equation that the final position z_f of the bridge is $Z_f = \frac{1}{3 \left[\frac{1}{z_3^3} - \frac{1440 W_{CIN}}{\pi^2 + c} \right]}$ Eq 30.

We can see in Figure 22 that depending on the acquired inertia, which depends on the energy provided by the Coulomb force, zf can slightly exceed its initial position. We will use this property at the end of this article in order to increase usable energy.



Figure 20: Positions of : 1/ The Final Rise z_r of the Structure, 2/ of the Point z_2 of Disappearance of the Coulomb Force Depending on the Threshold Voltage V_{T2} of Switch n°2, 3/ of the Point z_1 of Appearance of the Coulomb Force Depending on the Threshold Voltage V_{T1} chosen for Switch n°1

It is easy to calculate the damping energy W_{CASIMIR2} that appears between the intermediate position z_2 and the final position z_{f^*} . We have $W_{\text{CASIMIR2}} = \int_{z_2}^{z_f} F_{\text{CA}} dz = \int_{z_2}^{z_f} S \frac{\pi^2 + c}{240 z_s^4} dz_s = S \left(\frac{\pi^2 + c}{720}\right) \left[\frac{1}{z_f^3} - \frac{1}{z_2^3}\right]$ (Eq 31)

As, at position z_2 the switch n° 2 commutes to ON and puts the Coulomb electrode to ground through the RLC circuit below (Figure 21). The electrical charges present on the Coulombs electrode flow towards the ground, creating a current and a power which remains to be evaluated.



Figure 21: RLC Circuit to Power the Autonomous Electronics for Converting Power Peaks into Direct Voltage

We now evaluate this usable current flowing to ground. We put in the circuit, an adjustment capacitance C in series with C_{PIEZO} . We call $C_E = \frac{C_{PIEZO}C}{C_{PIEZO}+C}$ the equivalent capacity of the two capacities in series. When the switch n°2 commutes, we have the equation $U_C + U_L + U_R = C_{PIEZO} / Q_F = V_{T1}$ (figure 21), with $U_R = R I$, $U_L = L dI / dt$ and $Q_F = U_C C_{PIEZO}$.

With R representing resistance, L denoting inductance, and C indicating capacitance. After rearranging we have the following equation $\frac{d^2 U_C}{dt^2} + \frac{R}{L} \frac{dU_C}{dt} + \frac{U_C}{LC} = 0$ Eq 32.

This differential equation has solutions that depend on the value of its determinant. We choose the values of R, L, C in such a way that the determinant $\Delta = \sqrt{\left(\frac{R}{L}\right)^2 - \frac{4}{LC}} = 0$ of this equation is positive or vanishes. So, if $\Delta = 0$ the solution is : $x_1 = \frac{R}{2L}\left(-1 + \sqrt{1 - \frac{4L}{CR^2}}\right) = -\frac{R}{2L}$ and $x_2 = \frac{R}{2L}\left(-1 - \sqrt{1 - \frac{4L}{CR^2}}\right) = -\frac{R}{2L}$ then we have $x_1 = x_2 = -\frac{R}{2L} < 0$ Considering the

initial conditions, we obtain
$$u_c = \frac{V_{T1}}{x_1 - x_2} \left[x_1 \exp(x_2 t) - x_2 \exp(x_1 t) \right]$$
 Eq 33, $i_c = C \frac{du_c}{dt} = C \frac{V_{T1} x_1 x_2}{x_1 - x_2} \left[\exp(x_2 t) - \exp(x_1 t) \right]$

Eq34 The peak ofcurrent is given when $d(i_c)/dt = 0$ so at the time $t_{imax} = \frac{Ln(\frac{x_2}{x_1})}{x_1 - x_2} = \frac{Ln(\frac{1 + \sqrt{1 - CR^2}}{1 - \sqrt{1 - \frac{4L}{CR^2}}})}{\frac{R}{L}\sqrt{1 - \frac{4L}{CR^2}}}$ Eq 35 Replacing t

by t_{imax} in the equation 33 and 34 we obtain the expression for the maximum of the voltage is $u_{cmax} = V_{T1}$ and of the maximum current i_{cmax} ;



Figure 22 : Electric Voltage on the Capacitance C in Series with the Capacitance of the Coulomb Electrode



Figure 23: The Electric Current Flowing Through the Capacitance C in Series with the Capacitance of the Coulomb Electrode

The electrical power of the signal is :

$$P(t) = u_c i_c = \left(\frac{V_{T_1}}{x_1 - x_2}\right)^2 C x_1 x_2 \left[\exp(x_2 t) - \exp(x_1 t)\right] \left[x_1 \exp(x_2 t) - x_2 \exp(x_1 t)\right] \text{Eq36}$$



Figure 24: Electrical Power of the Signal to Power the Autonomous Electronics

We note on Figure 23 and 24 that the maximum $t_{imax} = 1.87 \ 10^{-10}$ (s) for the peak current is different than those $t_{pmax} = 3.03 \ 10^{-10}$ for the peak power P(t) The peak power of 1.93 mW is sufficient to power the autonomous electronics of figure 18,19 and obtain a useful voltage of several volts in a few milliseconds. The period of a vibration being (figure 10) of 0.2 µs for an F_{co} / F_{cA} of simply 2, the average power over a period is then approximately $\approx 0.3 \ \mu$ W.

We deduce that the power provided by the system in 1 second is of the order of $3e^{-7} / 2e^{-7} \approx 1.5$ W.

Knowing the electrical power P(time) we can numerically evaluate this finale and useable energy, by MATLAB. We obtain WELECTRIC in figure 27.

$$W_{ELECTRIC}(t) = \int_{0}^{10*t_{max}} u_c \, i_c \, dt = \left(\frac{v_{T1}}{x_1 - x_2}\right)^2 C \, x_1 x_2 \, \int_{0}^{10*t_{max}} [\exp(x_2 t) - \exp(x_1 t)] [x_1 \exp(x_2 t) - x_2 \exp(x_1 t)] \, dt \, \text{Eq37}$$

The energy balance is completed for the "return" phase to its initial position of the structure.

We have $W_{\text{RETURNING}} = W_{\text{CIN}} + W_{\text{ELECTRIC}} + W_{\text{DFCA2}} + W_{\text{BRIDGE2}} - W_{\text{CASIMIR2}} + \Delta Q_{\text{vib}} / 2$ (Eq 38)



Figure 25: Balance of the Energies of the "Go" and "Return" Phases for the Proposed MEMS which seems to be able to "Extract Energy from the Quantum Vacuum"

With Figure 25, we can make the energy balance of the energies provided by the quantum vacuum in the "going" and "returning" phases. The constant energy provided by the quantum vacuum ocean in the "go" phase simply changes its nature and subdivides into other energies in the "return" phase of vibrations. One of these energies in this "return" phase can be used by creating a little electrical energy. We note that the energy necessary for the perpetual maintenance of these vibrations is constantly provided by the isotropic and timeless energy of the quantum vacuum and that it is possible to extract from this gigantic ocean of energy of "nothing" a small electrical and exploitable energy. Whatever the F_{CO}/F_{CA} amplification factor, we note that $W_{RETURNING}$ is always slightly lower than E_{VACUUM} , thanks to the choice of $W_{ELECTRIC}$

We observed that in the referential of our 4 dimensions Space-Time plus the Quantic Vacuum, the energy is conserved which is consistent with Noether's theorem. This very important theorem of 1905 explains why, as Monsieur de Lavoisier said, "Nothing is created, nothing is lost, everything is transformed.".

Remember that energy is defined as the "physical quantity that is conserved during any transformation of an isolated system. However, the system constituted by simply the MEMS device in space is not an isolated system while the system constituted by the MEMS device plus the space plus the energy vacuum seems an isolated system. The part of the MEMS energy sensor vibrates at frequencies depending on the size of the structure and operating conditions, but with an amplitude of just a few Angstroms. These vibrations aren't perpetual motion; they can be continuously powered by vacuum energy from the Casimir force.

The following diagram summarizes the operation of this presented MEMS (Figure 26 and Figure 27)



Figure 26: Overview of the 5 Successive and Repetitive Steps of the M.E.M.S



Figure 27: Shape of the Curves Representing 1/ The Switching of the two Switches 2/ The Electrical Voltage on face 1 of the Piezoelectric Bridge 3/ The Casimir Forces F_{CA} 4/ The Coulomb Forces F_{co} 5/ the Energies W_{FCO} , W_{FCA} , W_{FCO} - W_{FCA} 6/ The Maximum Elevation z_f of the Moving Part

We notice in the previous pages that the piezoelectric bridge could reach a position z_f which exceeds its initial position z_0 . We can take advantage of this observation by modifying the moving part of this MEMS to provide the RLC ccircuit with the two signs of current peak and voltage emitted by the sensor. This modification should increase the continuous electrical voltage on the capacitive output of the autonomous electronic circuit whose role is to transform the signals from the quantum vacuum energy sensor(figure 28)



Figure 28: Shape of the MEMS Circuit Making it Possible to Double the direct Voltage at the Output of the Autonomous Electronic Circuit, by Providing it with Consecutive Voltage and Current Peaks of Opposite Sign



Figure 29: Positioning of 20 Casimir Cells in Parallel and 10 in series. Total of Casimir Cells Delivering a Periodic Current During a Small Part of the Vibration Frequency of the Devices = 200. Total Des Cellules = 200, Width = 5mm, Length = 7 mm

In order to obtain a current peak greater in intensity, the Casimir cells can be positioned in a series and parallel network at the 2 terminals of a single and as described RLC circuit for example, 20 Casimir cells can be placed in parallel and 10 in series ,(Figure 29).Important increase in current intensity, time duration of the peak, as of the voltage peak .This work on the energy balance of a M.E.M.S., which appears to be able to extract energy from a new, totally unexploited source, was carried out completely alone and without the help of any organization, by an old retiree. It seems that unless there is always a possible error - the fundamental theorem of EMMY NOETHER from 1905 is not contradicted. In the event of a theoretical confirmation by specialists, the supreme and definitive judgement will be the realization of a prototype, and I will be happy to participate in this development .

Autonomous Electronics to Transform the Cyclic Power Peaks from the R.L.C Circuit



Figure 30: Principle of the Single-Stage Doubler without Power Supply Electrical Diagram. All the MOS are Isolated from each other by Etching on an S.O.I Wafer, and their Threshold Voltage is as Close as Possible to Ground Power

The circuit of the figure 30 is an autonomous device operating without any electrical power source. It rectifies and accumulates the repetitive peak power delivered to the terminals of the RLC circuit in the figure 4 and 5 and transforms them into a usable direct voltage source. The impedance of the output of this autonomous circuit must be important .



Figure 31: SPICE Simulations of Voltages, Current, Power Consumed by the Autonomous Electronics for the Transformation into Direct Voltage (5.4 V) of an Alternating Input Signal of 50 mV, Frequency = 150 kHz, Number of Stages = 14, Coupling Capacities = 20 pF, Storage Capacity = 10 nF.

We note the extreme weakness of the electrical power required at the start of the conversion of the power peaks (60 nW) and at the end (2 pW). This transformation requires 4 ms .

CHARACTERISTICS OF OUTPUT VOLTAGES (V), POWERS (nW) CURRENTS (nA)

	Vg=50mV					Vg=100mV				
number of stages	Output Voltage	Current (nA) start end		Power (nW) start end		Output Voltage	Current (nA) start end		Power (nW) start end	
2*3	550mV	300n	26nA	15n W	1.3nW	1.1v	800nA	46nA	75nW	5nW
2*6	1	300nA	29nA	13nW	1.3nW	2V	700nA	67nA	60nW	6.5nW
2*14	2.20	300 nA	40nA	14nW	2.6nW	4,5v	700 nA	50nA	65 nW	4.8nW
2*21	2.8v	250nA	38nA	13nW	860pw	6v	600 nA	80nA	60nW	2.7nW
2*30	3.3	250nA	43nA	12nW	12nW	65V	750nA	85nA	61nW	4nW
2 * 3 9	3 <i>5</i> v	250nA	45nA	12nW	900pW	75V	750nA	95nA	64nW	3.5nW
2*48	3.6v	250nA	46nA	12nW	lnW	7.6V	750nA	100n A	60nW	4.2nW
2*60	3.8	270nA	47nA	12nW	1.1 nW	79V	700 nA	90nA	65nW	4.2nW
2*61	3.8	270nA	48nA	12.1n	1.3nW	8V	700nA	98nA	65 nW	42 nW

 Table 1: Output Continuous Voltage , with Current and Power Consumed by the Autonomous Electronic

 in Function of Two Input Cyclic Voltage Parametrized with the Number of Stages

The interesting points for the presented electronics' device are:

- the low alternative input voltages required to obtain a continuous voltage of several volts at the output
- the low power and current consumed by this conversion and amplification circuit on the source which in this case is only R.L.C. circuit, supplied by the current peaks generated by the autonomous vibrations.
- the rapid time to reach the DC voltage (a few tens of milliseconds)

The technology used to fabricate the MOSNE and MOSPE transistors with the lowest possible threshold voltages, is CMOS on intrinsic S.O.I. and each elements are isolated from each other on independent islands. This technology, represented in the following figure 54, strongly limits the leakage currents.

Grid Grid Drain Source N Bulk N Bulk	Metallic connection
S.O.I. wafer	

Figure 31: S.O.I Technology for Making the Elements of the "Doubler"

We note that, the coupling capacities of 20 pF of this electronic, like that of storage of the order of 10 nF, have relatively high values. To minimize the size of these capacitor we propose to use of titanium dioxide as insulator, with a relative permittivity of the order of 100 which is one of the most important for a metal oxide, then the size of the capacity passes to 33 μ m for a thickness of TiO2 = 500 A °, which is more reasonable.

Technology of Realization of the Current Extractor Device using the Forces of CASIMIR in a Vacuum

For the structures presented above, the space between the two surfaces of the reflectors must be of the order of 200 A °, which is not technologically feasible by engraving. Yet it seems possible to be able to obtain this parallel space of the order of 200 A ° between Casimir reflectors, not by etching layers but by making them thermally grow. Indeed, the S_{s3} and S_{s2} surfaces of the Casimir reflector must;

• be metallic to conduct the mobile charges

• insulating as stipulated by the expression of Casimir's law who established for surfaces without charges.

• This should be possible if we grow an insulator on the z direction of the structure, for example Al_2O_3 or TiO_2 or other oxide metal which is previously deposited and in considering the differences in molar mass between the oxides and the original materials.

For example, silicon has a molar mass of 28 g/mol and silicon dioxide SiO2 of 60 g/mol. It is well known that when a silicon dioxide SiO2 grows by one unit, a silicon depth of about 28/60 = 46.6%. This means that the fraction of oxide thickness "below" the initial surface is 46% of the total oxide thickness according to S.M. Sze. The same must happen, for example for thermal growth of alumina [9]. The molecular masses of Alumina and aluminium are $M_{AI2O3} = 102$ g/mole and MAI = 27 g/mole. We obtain an aluminium attack ratio of 27/102 = 26%, which implies that the original surface of this metal has shifted by 26% so that 74% of the alumina has grown out of the initial surface of the aluminium...

As regards the technological manufacture of electronics and structure, it therefore seems preferable:

• For electronics to choose Titanium Oxide because of its high relative permittivity $\epsilon_r = 114$ allowing to minimize the geometries required for the different capacities

• For the Casimir structure, the choice of aluminium, because its low density increases the resonant frequency of the structure and that 74% of the Alumina Al2O3 is outside the metal, allowing to reduce the interface between Casimir electrodes. A simple calculation shows for example that for aluminium gives : :



Figure 32: Distribution of Thicknesses

 $z_{od} = 2(z_{md} + z_{of} - z_{ma}) + z_o = 2[z_{md} + (1 - 0.26) z_{of} + z_o \Rightarrow z = z_{od} - 2(z_{md} + 0.74 z_{of})$

For example, we start from an opening $z_{od} = 3 \mu m$. We deposit a metal layer of aluminium that is etched leaving a width $z_{md} = 1 \mu m$ on each side of the reflector. Then an Alumina Al_2O_3 can grow, the thickness of which is precisely adjusted, simply by considerations of time, temperature, and pressure to increase a necessary thickness to have the desired interface z_0 . For example, if $z_0 = 200A^\circ$, $z_{od} = 3 \mu m$, $z_{md} = 1 \mu m$, then $z_{of} = 0.662 \mu m$. So, we obtain a Casimir interface of 200 A°. The final remaining metal thickness will be $z_{mf} = 0.338 \mu m$ and will act as a conductor under the aluminium oxide.

Obviously, the growth of this metal oxide between the electrodes of the Casimir reflector modifies the composition of the dielectric present between these electrodes, therefore of the mean relative permittivity of the dielectric.

Let: ε_0 be the permittivity of vacuum and ε_0 . ε_r the metal oxides one (ε_r = relative permittivity \cong 8 in the case of Al₂O₃), z_{of} the final oxide thickness on one of the electrodes and z the thickness of the vacuum present between electrode, (initially we want $z = z_0$).



For example, $z_{of} = 6620 \text{ A}^{\circ}$ is large compared to $z \le 2004 \text{ }^{\circ}$ therefore $\varepsilon_{om} \cong 8 * \varepsilon_{o}$ in the case of Al₂O₃.

We have considered this change in permittivity in the preceding simulations.

Steps for the Realization of the Structure and its Electronics

We use an SOI wafer with an intrinsic silicon layer : The realisation start with voltage "doubler" is obtained by using CMOS technology with 8 ion implantations on an SOI wafer to make :

• The sources, drains of the MOSNE, MOSND of the "doubler" and of the Coulomb force trigger circuits and of the grounding

- The source, drains of the MOSPE, MOSPD of the "doubler" and of the Coulomb force trigger circuits
- The best adjust the zero-threshold voltage of the MOSNE of the "doubler" circuit
- The best adjust the zero-threshold voltage of the MOSPE of the "doubler" circuit
- To define the threshold voltage of the MOSNE of the circuit n°1
- To define the threshold voltage of the MOSPE of the circuit n°1
- To define the threshold voltage of the MOSND of the circuit n°2
- to define the MOSPD threshold voltage of the circuit n°2
- This electronic done, we take care of the vibrating structure of CASIMIR
- engrave the S.O.I. silicon to the oxide to define the location of the Casimir structures (figure 33)



Figure 33 : 9/ Etching of S.O.I Silicon

• Place and engrave a protective metal film on the rear faces of the S.O.I wafer (figure 34)



Figure 34: 10/ Engraving of the Protective Metal Rear Face of the S.O.I. Silicon

• Deposit and engrave the piezoelectric layer (figure 35)



Figure 35: 11/Deposition and Etching of the Piezoelectric Layer Deposition and Etching of the Piezoelectric Layer

• Depose and etch the metal layer of aluminium (figure 36) .



Figure 36: 12/ Metal Deposit, Metal Engraving Etching of the Piezoelectric Layer

• Plasma etching on the rear side the silicon of the Bulk and the oxide of the S.O.I wafer protected by the metal film to free the Casimir structure then very finely clean both sides (figure 37)



Figure 37: 13/ View of the Casimir Device on the Rear Face, Engraving on the Rear Face of the Structures

• Place the structure in a hermetic integrated circuit support box and carry out all the bonding necessary for the structure to function.

• Carry out the thermal growth of aluminium oxide Al_2O_3 with a measurement and control of the circuit under a box. The electronic circuit should generate a signal when the interface between the Casimir electrodes becomes weak enough for the device to vibrate ... and then stop the oxidation. (Figure 38)



Figure 38: 15 /Adjusted Growth of Metal Oxide Front View of the Casimir Device and Coulomb's Electrode , Under Automatic Electronic Control

• Create a vacuum in the hermetic box

In the case where the 2 metal electrodes of Casimir, adhere to one another, they can be separated by the application of an electrical voltage on the Coulomb's electrodes.

Conclusion

The theoretical results of this project seem sufficiently encouraging to justify the development of prototypes. If its theoretical predictions are confirmed, it will trigger a scientific, technical and human revolution, because the quantum vacuum can be used as a new source of energy both on Earth and in space with a considerable commercial market.

As an inventor who has kept some details confidential, I would like to collaborate in its development after signing a contract with the potential investor

In the universe, everything is energy, everything is vibration, from the infinitely small to the infinitely large" Albert Einstein. "A person who has never made mistakes has never tried to innovate." Albert Einstein

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